



# Polymer-BiI<sub>3</sub> composites for high-performance, room-temperature, direct X-ray detectors

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## Abstract

Low-energy X-rays have a predominant role in medical diagnostic applications, grown tremendously during recent Covid-19 pandemic times. Synthesis of stable, PMMA/polystyrene-BiI<sub>3</sub> composites has been done through a facile, low-cost, dry-tumble mixing technique for direct X-ray detector applications. Comparative analysis of structural, optical, and photocurrent responses upon irradiation with low-energy X-rays (30 and 60 kV) ensue that PS-BiI<sub>3</sub> demonstrates high SNR 3300, sensitivity 189  $\mu\text{C Gy}^{-1} \text{cm}^{-3}$  and fast response time 30 ms, at dose rate 1.68  $\text{mGy s}^{-1}$ , affirming the composite to be prospective candidate for low-energy, room-temperature, direct X-ray detectors under low bias conditions.

## Introduction

Low-energy, pulsed X-rays are being used in many medical diagnostic applications like digital radiography, dental X-ray imaging, CT scan, and radiation therapy. In recent times of COVID-19 pandemic, X-ray-based imaging devices have been widely used for chest scans rendering the CT score value, a vital parameter for an early detection of deteriorating lung condition that has helped doctors to give a timely treatment to the Covid-positive patients saving many lives.<sup>[1]</sup> These spectacular applications are appealing and have given a new surge in the research of X-ray detector materials. Although many semiconductor and perovskite materials have carved a niche in the commercial X-ray detector industry, still the X-ray interactions with the detector material pose challenges to obtain stable, high detector performance with repeated usage. Researchers need to envisage new generation, light weight, portable, economically viable, easy-to-synthesize, X-ray detector materials possessing mechanical flexibility and capability of room-temperature operations with low power requirements. In this paper, we have synthesized polymer-BiI<sub>3</sub> composite pellets using a facile, soft effective method and investigated their performance for potential usage in direct X-ray detectors, capable of operating at room temperature, under low bias conditions.

X-ray detectors are broadly classified on two operation mechanisms, direct and indirect. Traditional semiconductor detectors are based on direct x-ray detection mechanism wherein the incident X-rays radiations are absorbed by the detector material and directly converted to charge carriers, generating an electric signal unlike the indirect detectors where the incident radiations fall on a scintillator material producing scintillating photons which further generate an electric signal. Direct X-ray detectors possess better signal-to-noise ratio

(SNR) and sensitivity and establish a stronger presence in the market. Compound semiconductors with wide bandgap show capability of room-temperature operations, notwithstanding the crystal defects and charge trapping that lead to performance deterioration. Direct conversion radiation detector materials should possess the following: (1) high density and high atomic number, since absorption coefficient ( $\alpha$ ) is proportional to  $Z^4/E^3$ , where  $Z$  and  $E$  denote the atomic number of material and radiation energy, respectively; (2) high  $\mu\tau$ , product of charge carrier mobility, and lifetime for efficient charge collection; (3) high resistivity to suppress the noise current; and (4) good stability for long-term operation.<sup>[2]</sup>

$\alpha$ -Se is the most prevalent direct conversion material used commercially in X-ray imaging devices, but poses certain limitations such as requirement of high operational voltage ( $10,000 \text{ V mm}^{-1}$ ) and decrease in the attenuation coefficient beyond X-ray energies of 40 keV.<sup>[3]</sup> Gallium arsenide being robust and stable makes a strong choice for imaging detectors; however, it shows poor energy resolution.<sup>[4]</sup> Cd-based detector materials such as cadmium telluride and cadmium zinc telluride exhibit good energy resolution and higher detection efficiency at high x-ray energies, but the main challenges with these materials are inconsistent performance at high x-ray flux, lower sensitivity, and high toxicity.<sup>[5]</sup> Recently, perovskite-based metal halides<sup>[6–9]</sup> like MAPbI<sub>3</sub> (methyl ammonium lead iodide) and Cs<sub>2</sub>AgBiBr<sub>6</sub> (dicesium silver bismuth hexabromide) are also emerging as potential candidates for modern detectors as they successfully demonstrate low dark current, high sensitivity at low energy doses, and a stable output over prolonged long usage.<sup>[10, 10]</sup> They display a linear response to X-ray energy and applied bias; however, high defect density, ion migration at high voltages, and poor environmental stability are a hindrance

in their practical applications.  $\text{Cs}_3\text{Bi}_2\text{I}_9$  is an excellent choice for x-ray detector due to its high sensitivity, low detection limit, dose rate linearity, and incredible detector properties;<sup>[12, 13]</sup> nevertheless, the detector performance parameters are highly dependent on the controlled synthesis method which is an expensive and sophisticated. Reliability and reproducibility of results with environmental stability are major challenge for these detectors in practical applications. Challenge still remains to find an economical, sturdy, non-toxic, and easy-to-synthesize material which demonstrates high-performance detector metrics.<sup>[14, 15]</sup>

In the past, bismuth tri-iodide ( $\text{BiI}_3$ ), a high density ( $5.78 \text{ g cm}^{-3}$ ), high atomic number (Bi:83, I:53) material offering high resistivity ( $10^8$  to  $10^{13} \Omega\text{-cm}$ ) and high attenuation, has shown magnificent results for lead-free, X-ray and gamma-ray detection applications.<sup>[16, 17]</sup> However,  $\text{BiI}_3$  has poor environmental stability and has a difficult growth process for defect free thick samples. In order to mitigate these shortcomings, we have, in our previous work, reported synthesis and preliminary investigations on polystyrene (PS)- $\text{BiI}_3$  composites and our results were indicative of good stability and prospects of the new composite for radiation detector.<sup>[18]</sup> The polymer matrix reinforces a level of stiffness in the otherwise easily cleavable layered pristine  $\text{BiI}_3$  and further increases the overall resistivity of the resultant composite thereby augmenting its performance parameters with remarkable improvement in detector stability. These results were encouraging and actuated us to carry out more studies on polymer- $\text{BiI}_3$  composites.

In the current work, we have synthesized and investigated the properties of poly-methyl methacrylate (PMMA)- $\text{BiI}_3$  and polystyrene (PS)- $\text{BiI}_3$  composites for being a radiation detector material and further compared its prospects vis a PS- $\text{BiI}_3$  samples. Photocurrent response of these composite pellets has been investigated with X-ray irradiation from two pulsed X-ray sources (60 kV and 30 kV) used in practical dental applications. PMMA- $\text{BiI}_3$  composite pellets showed sensitivity and SNR as  $94.6 \mu\text{C mGy}^{-1} \text{ cm}^{-3}$  and 1360, respectively, for dose rate of  $1.68 \text{ mGy s}^{-1}$  at 100 V and  $7.99 \mu\text{C Gy}^{-1} \text{ cm}^{-3}$  and 495, respectively, at dose rate of  $5.33 \text{ mGy s}^{-1}$  at voltage of 1.5 V. PS- $\text{BiI}_3$  composite showed better sensitivity and SNR values of  $189 \mu\text{C Gy}^{-1} \text{ cm}^{-3}$  and SNR 2300 for dose rate of  $1.68 \text{ mGy s}^{-1}$  for irradiation with X-ray energy of 30 kV. A considerable improvement to 3300 SNR was achieved with increase in dose rate to  $5.33 \text{ mGy s}^{-1}$  at 1.5 Volts though at a slightly compromised sensitivity of  $3.48 \mu\text{C Gy}^{-1} \text{ cm}^{-3}$ . It should be noted that this dose rate is the lowest for the X-ray source in our facility used for this work. As stated by the definition of the International Union of Pure and Applied Chemistry (IUPAC), detection limit of the device defined as the dose rate yielding an SNR value of 3 at a fixed bias which signifies that for prepared detector the actual detection rate is less than this value.<sup>[11]</sup> The photocurrent results demonstrated by polymer- $\text{BiI}_3$  composites suggest them to be prospective material for X-ray detection, offering good SNR response in the dose rate of  $3\text{--}5 \mu\text{Gy s}^{-1}$  at low voltage of 1.5 V as (most

X-ray diagnostics for medical applications are done below 5 mSv or  $5.5 \mu\text{Gy s}^{-1}$ <sup>[19]</sup>). Generally, such high SNR values are achieved at high bias voltage of the order of hundred voltage which reduces the stability of the detector. However, in our studies, we have successfully achieved high SNR at low voltage of 1.5 V.

## Materials and methods

### Synthesis of polymer- $\text{BiI}_3$ composite pellets

$\text{BiI}_3$  (purity >99.9%), PMMA, and PS granules were purchased from Sigma-Aldrich and polymer- $\text{BiI}_3$  composites were synthesized by simple dry-tumble technique with hot compression method. PMMA and PS granules were ground separately to fine powder in a liquid nitrogen environment using a grinder. Homogeneous composites were prepared by dry mixing the micron-sized crushed polymer powder with same-sized  $\text{BiI}_3$  powder at different weight percentage ratio of PMMA: $\text{BiI}_3$  (70:30, 60:40, 50:50, 40:60) and PS:  $\text{BiI}_3$  (50:50) and the nomenclature of the samples has been adopted accordingly as shown in Table I. The dry mixing was done without any solvent with constant stirring on a magnetic stirrer for 1 h at 400–500 rpm speed at room temperature. The solvent-free method prevents traces of any impurities due to no solvent residue left in the composite. The composite mixture was put into a stainless-steel die in a hot compression press and slowly heated to temperatures just below the softening temperature of the polymer 120 °C and 95 °C for PMMA and PS, respectively, maintaining the temperature for 15 min to achieve uniform heating and mixing of the composite powder. The mixture was then pressed with a pressure of  $50\text{--}60 \text{ kg cm}^{-2}$  to form a 1.2–1.5 mm thick compact pellet and let the composite gradually cool down to room temperature. The gradual heating and cooling process assists in the synthesis of a uniform and homogeneous composite with better crystallinity (Fig. 4 supplementary data). The as-prepared  $20 \times 10 \times 1.5 \text{ mm}^3$  pellets were cut into different rectangular dimensions for further characterization.

### Characterization and measurements

The X-ray diffraction studies of the samples were done using  $\text{CuK}\alpha 1$  radiation in the  $2\theta$  range of  $10^\circ\text{--}50^\circ$ . The optical studies of the samples were done using Double

**Table I.** Nomenclature of samples according to weight % composition of PMMA, PS, and  $\text{BiI}_3$ .

Sample name	$\text{BiI}_3$ wt%	Polymer wt%
PMMA-70	30%	PMMA 70%
PMMA-60	40%	PMMA 60%
PMMA-50	50%	PMMA 50%
PMMA-40	60%	PMMA 40%
PS-50	50%	PS 50%

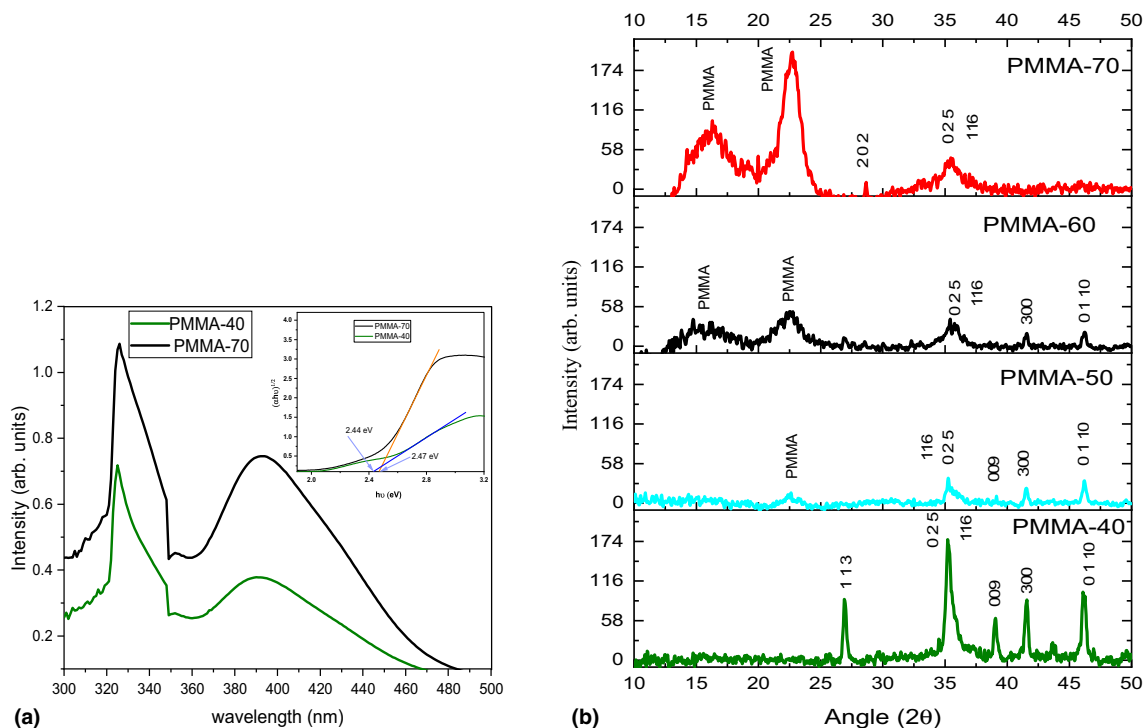
Beam Cary 100 UV–Vis spectrometer within the spectral range of 200–800 nm. The morphology of the surface as well as cross-sectional and top view across the thickness of the pellet have been performed by ICM-7000 Jeol Scanning Electrode Microscope with an EDAX. To study the X-ray detection response, the composite pellets were placed at 15 cm from the X-ray source and were irradiated using two different pulsed, DC X-ray sources operating at 30 kV (tube current 10 mA, pulse width 4 s,  $1.68 \text{ mGy s}^{-1}$  dose rate) and 60 kV (tube current 8 mA, pulse width 1.5 s, dose rate of  $5.33 \text{ mGy s}^{-1}$ ) in on/off states. The X-rays are made to exit from the source through 1.5 mm thick Al foil filters. The dose rate (D) for the source is calculated by formula (1) in supplementary data.

The photocurrent measurements were done using an Keithley-6485 Picometer with silver electrodes deposited on the 1.5 mm thick detectors in perpendicular configuration. The interaction of X-rays with detector material strongly depends on the stopping power or the attenuation coefficient of the material. The mass attenuation coefficient of the composite at a particular energy was calculated by NistXcom software (<https://physics.nist.gov/PhysRefData/Xcom/html/xcom1.html>) and was multiplied by the weighted average density of the composite to obtain linear attenuation coefficient of the material. The absorbance/attenuation of radiation as calculated from Eq. (2) in supplementary was upto 95% for our samples.

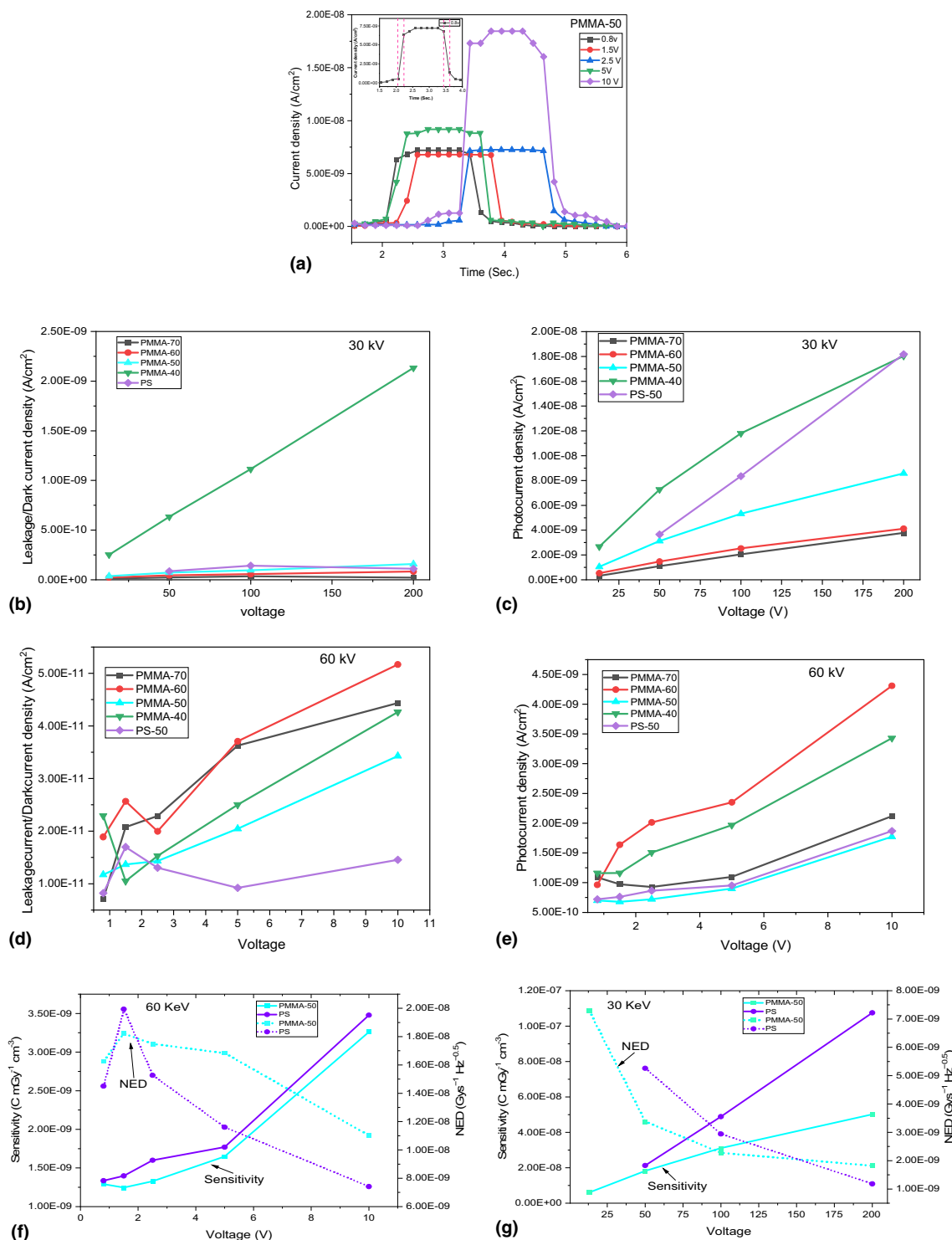
## Results and discussion

### UV spectroscopy, X-ray diffraction and SEM studies

The UV absorption spectra of the samples PMMA-40 and PMMA-70 as depicted in Fig. 1(a) were recorded after dissolving the pellet in acetone solvent. The polymer PMMA functional OH-group formed bond with Iodine (I) in  $\text{BiI}_3$  in solid pellet matrix but when we dissolve the pellet in solvent, the OH-I bond weakened and got two different peaks.<sup>[20]</sup> These two are very similar to the pristine  $\text{BiI}_3$  absorption peaks (Fig. 2 supplementary data) with a blue shift that indicates the formation of composite. The spectra show onset of absorption in the range of 450–480 nm with a broad peak and another sharp transition edge at 350 nm which progresses to peak at 330 nm. There is an I-OH bond formation in our composite samples. An increase in  $\text{BiI}_3$  weight percentage from 30 to 60% leads to a decreased concentration of I–OH bonding. This leads to changes in the nature of intermolecular bands within the spectrum which may act as defect or trap states thereby leading to the difference in the onset of absorption leading to the peak shift. The bandgap for the PMMA- $\text{BiI}_3$  composites as calculated from Tau plot [inset in Fig. 1(a)] is 2.44 eV which lies between the bandgap values of its constituents ( $\text{BiI}_3$ , 2.0 eV, and PMMA, 4.8 eV) and is also the desired bandgap for X-ray detector materials. An increase in the concentration of PMMA from 40 to 70% leads to a substantial increase in the absorption peak intensity at 390 nm and furthermore, the onset of



**Figure 1.** (a) UV–Vis absorption spectra of PMMA-70 and PMMA-40 samples, inset: tau plot for band gap (b) XRD pattern of polymer- $\text{BiI}_3$  composites at varied ratios for PMMA-40,50,60,70.



**Figure 2.** Photocurrent studies for PMMA and PS composite samples for X-ray irradiation at 60 kV and 30 kV. (a) Photocurrent versus time response (inset depicts the rise and fall time of the response curve for PMMA-50), (b, c, d, and e) Leakage current density and photocurrent density versus bias voltage for polymer-BiI<sub>3</sub> composites. (f, g) Sensitivity and NED response of best results PMMA-50 and PS-50 samples at 60 kV and 30 kV, respectively (solid lines represent sensitivity and dotted lines represent NED).

absorption gets slight red shifted from 470 to 480 nm. The broad band from 350 to 480 nm may be attributed to the presence of defects, color-centers, and vacancies leading to trapping of electrons and holes.<sup>[21]</sup>

X-ray diffraction patterns of the composite samples synthesized with varied compositional ratios depicted in Fig. 1(b) show multiple peaks corresponding to PMMA and BiI<sub>3</sub>. Pure PMMA gives two broad peaks at around 14° and 21.6°, which is seen shifted at around 15.5° and 22.5° in our samples, suggestive of compressive stress induced during the composite formation.<sup>[22]</sup> The peak at around 35.1° is a merged peak of (025) and (202) BiI<sub>3</sub> planes and is clearly evident as a shoulder in the pattern for PMMA-70. This peak along with (300) peak corresponds to the tetragonal phase with space group P3/m of BiI<sub>3</sub> (compared with JPCDS card no. #76-1742). Further, the (0110) and (009) peaks represent hexagonal phase of BiI<sub>3</sub> asserting mixed phases in our samples (JPCDS card no. #48-1795). It is worth mentioning here that with increasing polymer content, the BiI<sub>3</sub> peaks diminish and there is a gradual progression toward amorphous nature in the composite formation. The PMMA-50, 60 patterns expose well-defined crystalline peaks for both PMMA and BiI<sub>3</sub> evincing the fact that BiI<sub>3</sub> crystallites are homogeneously embedded near the surface in the PMMA matrix. These samples pre-eminently show well-balanced properties of both BiI<sub>3</sub> and PMMA, ensuing better charge collection efficiency for a wider range of voltages as can be corroborated with our results later.

The surface morphology of the PMMA-50 sample given in Fig. 3 (supplementary data) showed a homogeneous composite with a sheet structure rolled in at the edges corresponding of PMMA with small BiI<sub>3</sub> crystallites sparsely spread all over the surface of the sheet and at the boundaries of the folds. Cross-sectional micrograph gives the average thickness of the sample as 1.5 mm. The energy-dispersive X-ray analysis of the sample portion marked in red as SPC001 showed the presence of bismuth and iodine peaks thereby corroborating our XRD results. Further, SEM study of the sample revealed no structural changes after continuous sun exposure of the sample for over 60 min, and more so no impairment in the features was found even after being kept under high humidity (RH 70–90%) and high temperature (30–35°C) conditions for 2 months asserting the environmental stability of the samples. EDAX studies confine homogenous composite across sample and its cross-section (Fig. 4 in supplementary data).

### Photocurrent and performance metrics analysis

We have investigated the detector performance parameters like photocurrent, leakage/dark current, SNR, sensitivity, and noise-equivalent dose (NED) for PMMA-BiI<sub>3</sub> and PS-BiI<sub>3</sub> composites synthesized with different ratios. However, analysis of PS composite results conclusively declared PS-50 to be the best sample in terms of low leakage current, high photocurrent, and high SNR. Therefore, to maintain brevity of the manuscript, comparative results for PMMA composites vis a vis PS-50 have

been cited. The photocurrent and dark-current responses upon irradiation with two different X-ray sources (60 kV, 8 mA) and (30 kV, 10 mA) at different bias voltages are depicted in Fig. 2(a–f). Photocurrent time response of PMMA-50 sample shows a sharp rise and fall with switching on/off of the X-ray source in Fig. 2(a) [photo-response for 30 kV of PMMA-50 sample is included in supplementary data Fig. 5(b)] and calculations yield a fast response time of around 30 ms (inset Fig. 2a). Fast response/recovery time is highly desired in medical applications for improved image resolution and reduced X-ray exposure. A point worth mentioning here as an advantage of our results is the requirement of low bias voltage (1–10 V) to achieve substantial photocurrent values at X-ray energy, 60 kV. High bias conditions adversely affect the photocurrent signal due to polarization effects induced in the sample. Figure 2(b–e) displays a nearly linear response between the photocurrent and dark-current signals versus bias voltage in our samples and further reveals reduction in the signals by an order of 1 to 2 with increase in X-ray energy from 30 to 60 kV. For an ideal detector, high photocurrent and low leakage current are key parameters to appraise the detector performance, and PMMA-40 and PMMA-60 samples demonstrated a high photocurrent, but on the flipside showed unfavorably high leakage current. PMMA-50 exhibited minimum leakage-current density,  $1.17 \times 10^{-11}$  A cm<sup>-2</sup> (at 0.8 V, 60 kV) and  $3.68 \times 10^{-11}$  A cm<sup>-2</sup> (at 13 V, 30 kV) bias voltage. The photocurrent signals recorded for PMMA-50 was of the order of  $7 \times 10^{-10}$  A cm<sup>-2</sup> (at 0.8 V, 60 kV) and  $3.13 \times 10^{-09}$  A cm<sup>-2</sup> (at 50 V, 30 kV). Although PMMA-50 offers low photocurrent densities, smaller standard deviation, low leakage current, and better SNR that are reasonable trade-off in detector performance parameters, consequently making PMMA-50, the optimal sample in the PMMA series. However, comparison between PMMA-50 and PS-50 rendered better results for the latter, with PS-50 displaying lower leakage current,  $8.21 \times 10^{-12}$  A cm<sup>-2</sup> (at 0.8 V, 60 kV) and comparable photocurrent densities,  $7.2 \times 10^{-10}$  A cm<sup>-2</sup> (at 0.8 V, 60 kV) and  $3.66 \times 10^{-09}$  A cm<sup>-2</sup> (at 50 V, 30 kV). High photocurrent and low leakage currents offered by PS-50 make it a prospective choice for the detector. PS-50 photocurrent response for 60 kV is given in supplementary data (Fig. 5). Signal-to-noise ratio (SNR), sensitivity, and noise-equivalent dose rate (NED) are crucial assessment parameters for a detector and are calculated with formulas given in supplementary data.

A detector should possess a low NED value for better quality, high contrast imaging, which is an important parameter for practical medical applications.<sup>[21]</sup> Calculations for sensitivity, SNR, and NED have been done for dose rates, (D) of  $5.33$  mGy s<sup>-1</sup> (60 keV source) and  $1.68$  mGy s<sup>-1</sup> (30 kV source). Highest achieved sensitivity and SNR for different dose rates and bias conditions by PMMA composites in our work are mentioned in sequence as follows: ( $94.6$  μC mGy<sup>-1</sup> cm<sup>-3</sup>, 1360 for dose rate  $1.68$  mGy s<sup>-1</sup>, at 100 V) and ( $7.99$  μC Gy<sup>-1</sup> cm<sup>-3</sup>, 495, for dose rate of  $5.33$  mGy s<sup>-1</sup>, at 1.5 V). PS-50 composites showed best sensitivity and SNR values as ( $189$  μC Gy<sup>-1</sup> cm<sup>-3</sup>, 2300 for dose rate of  $1.68$  mGy



**Table II.** Comparison of sensitivity results for PMMA and PS composites in this work with other published data.

Material	Sensitivity ( $\mu\text{C Gy}^{-1} \text{cm}^{-3}$ )	X-ray tube voltage (kV)	Dose rate ( $\text{mGy s}^{-1}$ )	Voltage/electric field	Ref.
CsPbI <sub>3</sub> : PVDF-HFP	4.7	70	2.5	2 V	[24]
BiI <sub>3</sub>	0.053	70	2.5	2 V	[25]
Bi <sub>5</sub> O <sub>7</sub> I	1.926	70	2.5	2 V	[26]
TMCM-CdCl <sub>3</sub>	128.9±4.64 $\mu\text{C Gy}^{-1} \text{cm}^{-2}$	40	1.06 $\mu\text{Gy}^{-1} \text{s}^{-1}$	10 V	[27]
$\omega$ -Bi <sub>2</sub> O <sub>3</sub>	3.077 $\mu\text{CGy}^{-1} \text{cm}^{-2}$	60	56.95 $\mu\text{Gy}^{-1} \text{s}^{-1}$	20 V	[28]
CsPbI <sub>3</sub>	83.6 $\mu\text{C Gy}^{-1} \text{cm}^{-2}$	60	1.7	0.17 V $\mu\text{m}^{-1}$	[29]
Y <sub>2</sub> O <sub>3</sub> (high temp.)	0.143	70	2.5	2 V	[30]
Fe doped $\beta$ -Ga <sub>2</sub> O <sub>3</sub>	23.2 nC Gy <sup>-1</sup>	30	0.383 Gy s <sup>-1</sup>	800 V	[23]
PMMA-BiI <sub>3</sub>	94.6	30	1.68	200 V	This work
PMMA-BiI <sub>3</sub>	7.99	60	5.33	10 V	This work
PS-BiI <sub>3</sub>	189	30	1.68	200 V	This work
PS-BiI <sub>3</sub>	3.48	60	5.33	10 V	This work

s<sup>-1</sup>, at 100 V) and (3.48  $\mu\text{C Gy}^{-1} \text{cm}^{-3}$ , 3300, for dose rate of 5.33  $\text{mGy s}^{-1}$ , at 1.5 V) indicating an exceptionally high SNR of 3300, though at a slightly compromised sensitivity of 3.48  $\mu\text{C Gy}^{-1} \text{cm}^{-3}$ . The highest sensitivity accomplished in our work surpasses that of commercially available  $\alpha$ -Se detectors, which is 20  $\mu\text{Gy}^{-1} \text{cm}^{-2}$  at 10,000 V. Sensitivity and NED values for PMMA-50 and PS-50 are (3.26  $\mu\text{Gy}^{-1} \text{cm}^{-3}$ ,  $1.10 \times 10^{-8} \text{Gys}^{-1} \text{Hz}^{-0.5}$ ) and (3.48  $\mu\text{Gy}^{-1} \text{cm}^{-3}$ ,  $7.42 \times 10^{-9} \text{Gys}^{-1} \text{Hz}^{-0.5}$ ), respectively, The sensitivity in our samples is much higher than the reported relative sensitivity value of 23.2  $\mu\text{C Gys}^{-1}$  for  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> MSM detector at 800 V bias voltage and also better than the value, 21.8 nC Gy<sup>-1</sup>, reported for  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> SBD detector at 10 V. Enumerating further, the NED values of PMMA-50 and PS-50 samples are lower by an order of 2 and outperform the reported NED values for  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> MSM detector ( $4.13 \times 10^{-7} \text{Gys}^{-1} \text{Hz}^{-0.5}$ ) and  $\beta$ -Ga<sub>2</sub>O<sub>3</sub> SBD detector ( $8.69 \times 10^{-7} \text{Gys}^{-1} \text{Hz}^{-0.5}$ ).<sup>[23]</sup> A comparative table with sensitivity values for our samples vis a vis those reported in recent literature reports is given in Table II.

High SNR, better sensitivity, and low NED, more so at low bias conditions, all together make polymer-BiI<sub>3</sub> composites, the preferred choice for high imaging X-ray detectors in medical diagnostics. PS composites that have an edge over PMMA composites exhibiting better response for 60 kV X-ray source such as high sensitivity, SNR, low dark current, and NED for response. On the contrary, PMMA composite with a higher mass attenuation for low energies showed faster rise and fall response at low voltages. Further, the standard deviation of photocurrent of optimized composite samples was found 0.21% for PMMA-50 and 0.02% for PS, which is way less than the standard value (10%). PS-BiI<sub>3</sub> samples proved to be more environmentally stable with longer operational life as the OH<sup>-</sup> group in the PMMA samples causes rusting under ambient and humid conditions arising the need for surface cleaning before doing photocurrent measurements. Also, these polymers being thermostatic can be reused over repeated cycles with reliability which is a problem with halide-based detectors.

## Conclusion

To conclude, a low-cost solvent-free method has been used to prepare lead-free, PMMA/PS- BiI<sub>3</sub> composite pellets of thickness 1.5 mm, which displays attenuation upto 95% of incident X-rays. Both polymer composites showed promising results for room-temperature X-ray detector operation under low bias conditions with good environmental stability. But among both, PS-50 showed outstanding results of x-ray response for both 30 and 60 kV X-rays with better environmental stability. The sensitivity achieved for PS-50 was 189  $\mu\text{C Gy}^{-1} \text{cm}^{-3}$  which is nine times better than the commercially available  $\alpha$ -Se (20  $\mu\text{C Gy}^{-1} \text{cm}^{-2}$ ). Also, the SNR, 3300 demonstrated by the PS-50 composite at 1.5 V biased voltage holds great promise for fabrication of a good X-ray imaging device with high resolution at low bias voltages. The response and recovery time of the detector is fast around 30 ms. The reliability of these materials is high owing to smaller standard deviation in photocurrent as well as noise current measurements. These results suggest that the PMMA/PS -BiI<sub>3</sub> composites, exhibiting fabulous properties, are a fantastic candidate for room-temperature, low-voltage, radiation detector devices. Yet, sensitivity of the sample further needs to be improved, which can be achieved by using conductive fillers to increase the photocurrent.

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## Declarations

## Conflict of interest

The authors have no conflict of interests relevant to this article.

## Supplementary Information

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